

UNISONIC TECHNOLOGIES CO., LTD

05N45 **Preliminary Power MOSFET**

0.5A, 450V N-CHANNEL **POWER MOSFET**

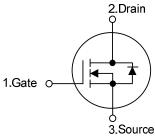
DESCRIPTION

The UTC 05N45 is an N-channel mode power MOSFET using UTC's advanced technology to provide customers with a minimum on-state resistance, low gate charge and superior switching performance.

FEATURES

- * $R_{DS(ON)} \le 11\Omega$ @ $V_{GS}=10V$, $I_{D}=0.25A$
- * High switching speed
- * 100% avalanche tested

SYMBOL





ORDERING INFORMATION

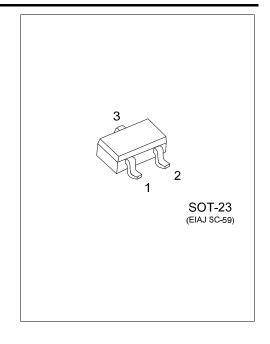
Ordering Number		Dookogo	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
05N45L-AE3-R	05N45G-AE3-R	SOT-23	G	S	D	Tape Reel	

Note: Pin Assignment: S: Source G: Gate D: Drain



MARKING





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■ **ABSOLUTE MAXIMUM RATINGS** (T_C=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Drain-Source Voltage	V _{DSS}	450	V
Gate-Source Voltage	V _{GSS}	±30	V
Continuous Drain Current	I _D	0.5	Α
Pulsed Drain Current (Note 2)	I _{DM}	2.0	Α
Power Dissipation	P _D	1.14	W
Junction Temperature	TJ	+150	°C
Storage Temperature	T _{STG}	-55 ~ + 150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ **ELECTRICAL CHARACTERISTICS** (T_J =25°C, unless otherwise specified)

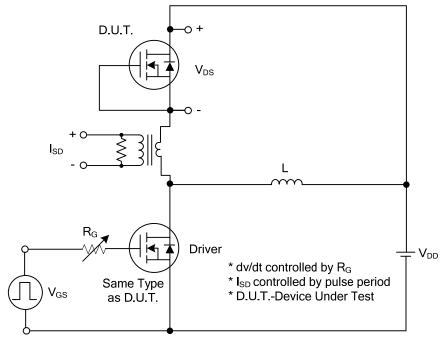
PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage		BV_{DSS}	I _D =250μA, V _{DS} =0V	450			V
Drain-Source Leakage Current		I _{DSS}	V _{DS} =450V			1	μΑ
Gate-Source Leakage Current	Forward		V_{GS} =+30V, V_{DS} =0V			100	nA
	Reverse	I_{GSS}	V_{GS} =-30V, V_{DS} =0V			-100	nA
ON CHARACTERISTICS							
Gate Threshold Voltage		$V_{GS(TH)}$	I _D =250μA	2.0		4.0	V
Static Drain-Source On-State Resistance		R _{DS(ON)}	V _{GS} =10V, I _D =0.25A			11	Ω
DYNAMIC PARAMETERS							
Input Capacitance		C_{ISS}			172		pF
Output Capacitance		Coss	V_{GS} =0V, V_{DS} =25V, f=1MHz		17		pF
Reverse Transfer Capacitance		C_{RSS}			4.6		pF
SWITCHING PARAMETERS							
Total Gate Charge (Note 1)		Q_G	\/ -E0\/ \/ -10\/ -1.2A		12		nC
Gate to Source Charge		Q_GS	V _{DS} =50V, V _{GS} =10V, I _D =1.3A I _G = 100µA (Note1, 2)		0.8		nC
Gate to Drain Charge		Q_GD	IG- 100μΑ (Note1, 2)		0.8		nC
Turn-ON Delay Time (Note 1)		$t_{D(ON)}$			14		ns
Rise Time		t_R	V_{DS} =30V, V_{GS} =10V, I_{D} =0.5A,		26		ns
Turn-OFF Delay Time		t _{D(OFF)}	R _G =25Ω (Note1, 2)		86		ns
Fall-Time		t_{F}			51		ns
SOURCE- DRAIN DIODE RATIN	NGS AND CH	ARACTERIS [®]	TICS				
Maximum Body-Diode Continuous Current		Is				0.5	Α
Maximum Body-Diode Pulsed Current		I _{SM}				2.0	Α
Drain-Source Diode Forward Voltage (Note 1)		V_{SD}	I _S =0.5A, V _{GS} =0V			1.4	V

Notes: 1. Pulse Test : Pulse width ≤450µs, Duty cycle ≤2%.

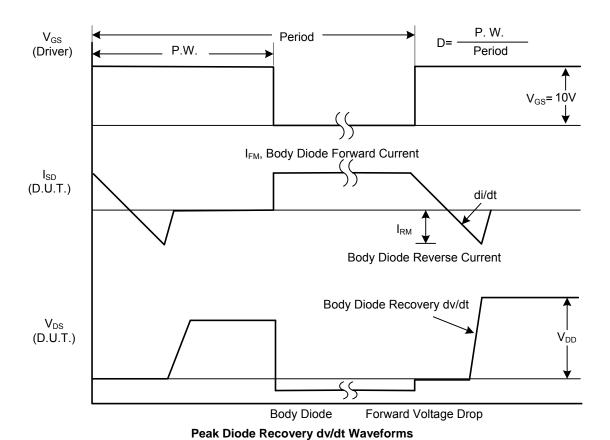
^{2.} Repetitive Rating: Pulse width limited by maximum junction temperature.

^{2.} Essentially independent of operating temperature.

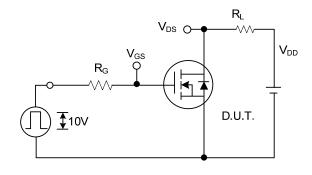
■ TEST CIRCUITS AND WAVEFORMS

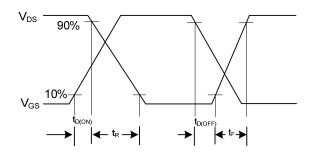


Peak Diode Recovery dv/dt Test Circuit



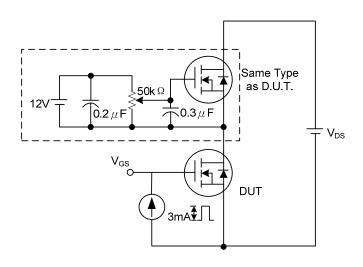
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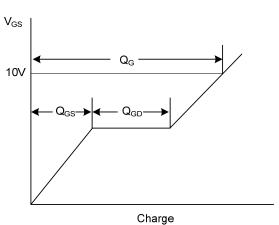




Switching Test Circuit

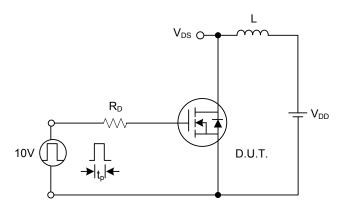
Switching Waveforms

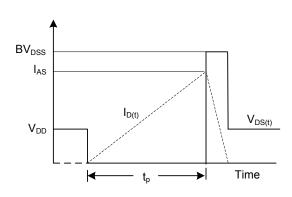




Gate Charge Test Circuit

Gate Charge Waveform





Unclamped Inductive Switching Test Circuit

Unclamped Inductive Switching Waveforms

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